ΡΛΝ	ĴΪΤ
	SEMI CONDUCTOR

### 20V N-Channel Enhancement Mode MOSFET – ESD Protected

0.5A

Current

### Features

Voltage

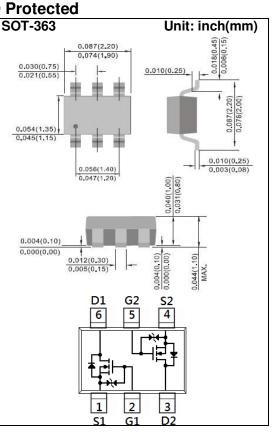
- RDS(ON) , VGS@4.5V, ID@0.5A<0.4Ω
- RDS(ON) , VGS@2.5V, ID@0.3A<0.7Ω
- RDS(ON) , VGS@1.8V, ID@0.1A<1.2Ω(typ.)

20 V

- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std.(Halogen Free)

#### **Mechanical Data**

- Case : SOT-363 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0002 ounces, 0.006 grams
- Marking : T02



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	20	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 12	V
Continuous Drain Current		I <sub>D</sub>	0.5	А
Pulsed Drain Current (Note 4)		I <sub>DM</sub>	2.0	А
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	350	mW
	Derate above 25°C		2.8	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	357	°C/W



## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static		-		_		
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}$ =0V, I <sub>D</sub> =250uA	20	-	-	V
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	0.4	0.63	1.0	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS}$ =4.5V,I <sub>D</sub> =0.5A	-	0.32	0.4	Ω
		V <sub>GS</sub> =2.5V,I <sub>D</sub> =0.3A	-	0.6	0.7	
		V <sub>GS</sub> =1.8V,I <sub>D</sub> =0.1A	-	1.2	-	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =16V, $V_{GS}$ =0V	-	0.02	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm 10V, V_{DS}=0V$	-	<u>+</u> 2	<u>+</u> 10	uA
Dynamic (Note 5)						
Total Gate Charge	Qg	$V_{DS}$ =10V, I <sub>D</sub> =0.5A, $V_{GS}$ =4.5V <sup>(Note 1,2)</sup>	-	0.9	-	nC
Gate-Source Charge	$Q_gs$		-	0.3	-	
Gate-Drain Charge	$Q_gd$		-	0.1	-	
Input Capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	39	-	pF
Output Capacitance	Coss		-	18	-	
Reverse Transfer Capacitance	Crss		-	9	-	
Turn-On Delay Time	$td_{(on)}$		-	3	-	
Turn-On Rise Time	tr	$V_{DD}$ =10V, I <sub>D</sub> =0.5A, $V_{GS}$ =4.5V, $R_{G}$ =6 $\Omega$ <sup>(Note 1,2)</sup>	-	22	-	ns
Turn-Off Delay Time	$td_{(off)}$		-	7	-	
Turn-Off Fall Time	tf	n <sub>G</sub> =012	-	19	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>		-	-	0.4	А
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =0.5A, V <sub>GS</sub> =0V	-	0.91	1.3	V

NOTES :

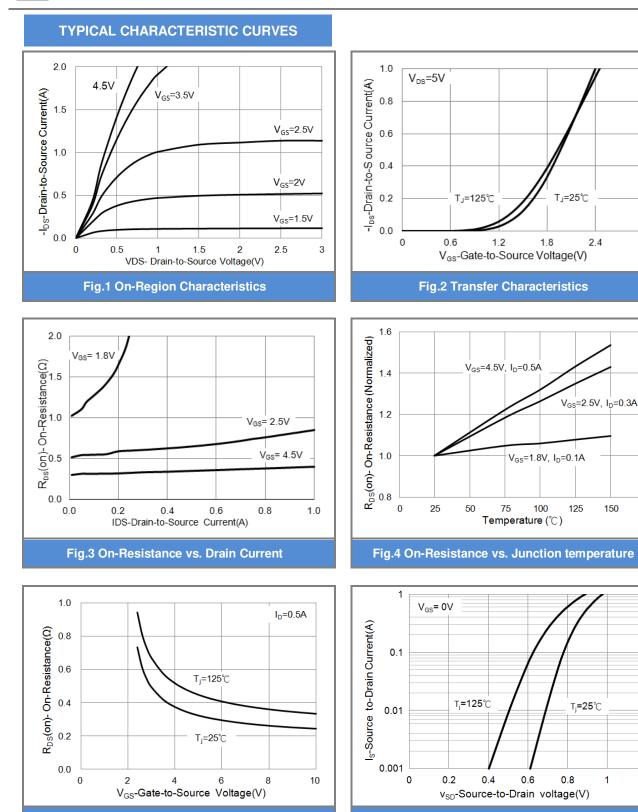
1. Pulse width</br>

2. Essentially independent of operating temperature typical characteristics.

3. R<sub>®JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper

- 4. The maximum current rating is package limited
- 5. Guaranteed by design, not subject to production testing





3

150

1

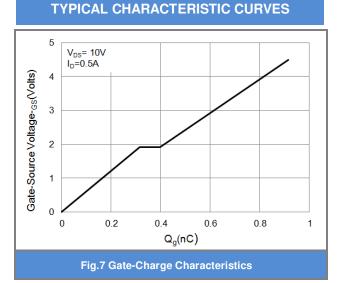
Fig.6 Body Diode Characteristics

1.2

175

Fig.5 On-Resistance Variation with VGS.





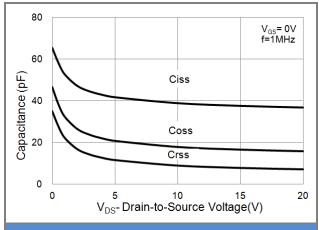
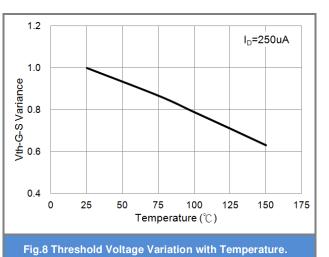


Fig.9 Threshold Voltage Variation with Temperature.



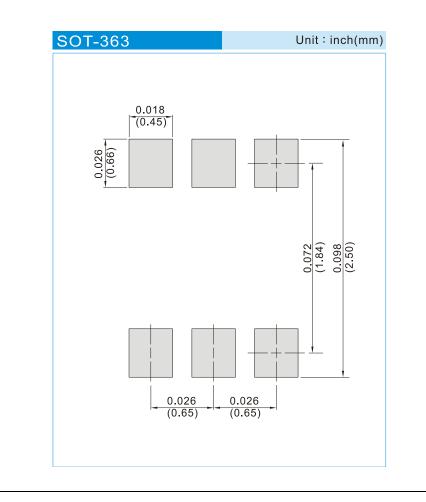




### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJT7802_R1_00001	SOT-363	3K pcs / 7" reel	T02	Halogen free
PJT7802_R2_00001	SOT-363	10K pcs / 13" reel	T02	Halogen free

### MOUNTING PAD LAYOUT





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